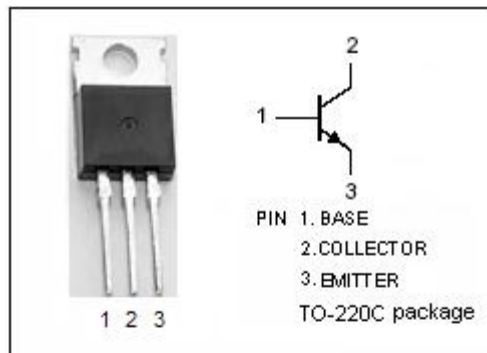


**isc Silicon NPN Power Transistor**
**2SC4273**
**DESCRIPTION**

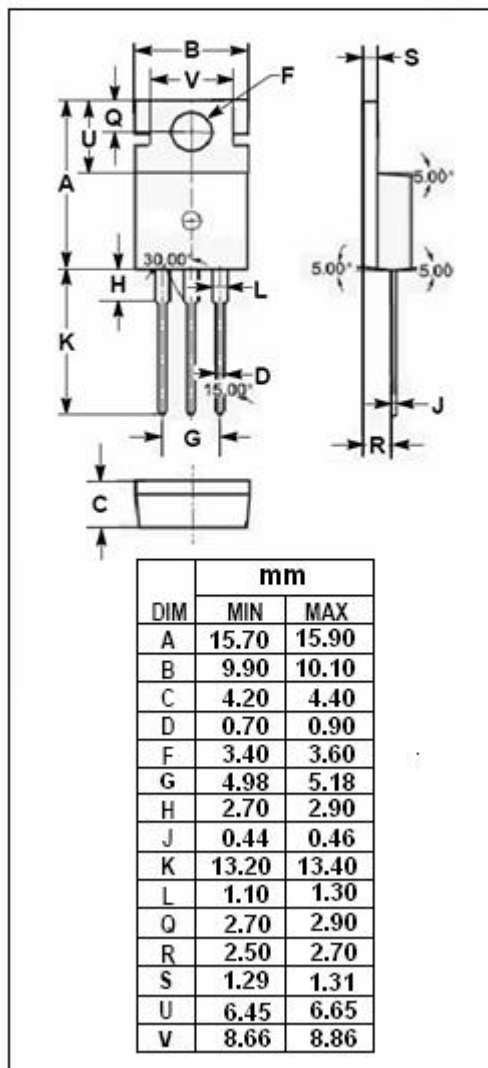
- High Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 400V(\text{Min})$
- High Switching Speed
- High Reliability
- Low Collector Saturation Voltage
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Switching regulators
- DC-DC converter
- Solid state relay
- General purpose power amplifiers


**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	500	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base voltage	10	V
$I_C$	Collector Current-Continuous	5	A
$I_B$	Base Current-Continuous	2	A
$P_C$	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	40	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$


**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{thj-c}$	Thermal Resistance, Junction to Case	3.0	$^\circ\text{C/W}$

**isc Silicon NPN Power Transistor**
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**ELECTRICAL CHARACTERISTICS**
 $T_c=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=0.2\text{A}; I_B=0$	400			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C=1\text{mA}; I_E=0$	500			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E=1\text{mA}; I_C=0$	10			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=2\text{A}; I_B=0.4\text{A}$			0.8	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=2\text{A}; I_B=0.4\text{A}$			1.2	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB}=450\text{V}; I_E=0$			0.1	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}=10\text{V}; I_C=0$			0.1	mA
$h_{FE}$	DC Current Gain	$I_C=0.5\text{A}; V_{CE}=5\text{V}$	25		55	

## Switching times

$t_{on}$	Turn-on Time				1.0	$\mu\text{s}$
$t_{stg}$	Storage Time	$I_C=2.5\text{A}, I_{B1}=0.25\text{A}; I_{B2}=-0.5\text{A};$ $R_L=60\Omega; P_W=20\mu\text{s};$ Duty Cycle $\leq 2\%$			2.5	$\mu\text{s}$
$t_f$	Fall Time				0.5	$\mu\text{s}$

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